

**AMENDMENTS TO THE SPECIFICATION**

***In the Specification:***

Please **REPLACE** paragraph [0007] with the following amended paragraph:

[0007] Conventionally, the driving transistors 113, 123 and 133 of the R, G and B unit pixels 110R, 120G and 130B of an ~~OLED~~OLED have the same size, that is, the same ratio W/L of the width W to the length L of the channel layer, and the order of the EL devices in the order of their luminous efficiency is B, R and G unit pixels. In the conventional OLED, since the sizes of the channel layers of the driving transistors 113, 123 and 133 in the R, G, and B unit pixels 110R, 120G and 130B are same while the luminous efficiencies of R, G and B EL devices 115, 125 and 135 are different from one another, it was difficult to embody the white balance.

Please **REPLACE** paragraph [0037] with the following amended paragraph:

[0037] Figs. 2A, 2B, 2C, and 2D are views showing a method of manufacturing driving transistors of R, G and B unit pixels in accordance with an embodiment of the present invention. Sectional structures of Figs. 2A, 2B, 2C and 2D ~~illustrate the~~illustrate the driving transistors among the R, G and B unit pixels of each pixel in an organic light emitting diode.